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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

			FDF 11.117 280
In re PATENT application of)	700 700
Jun KOYAMA et al.)	
Serial No. 09/757,778)	Art Unit: 2871
Filed:	January 9, 2001)	Examiner: T. Duong
For:	ACTIVE MATRIX LIQUID CRYSTAL DISPLAY)	
	AND METHOD OF FABRICATING SAME)	

TERMINAL DISCLAIMER

Honorable Assistant Commissioner for Patents Washington, D. C. 20231

Sir:

SEMICONDUCTOR ENERGY LABORATORY CO., LTD., a corporation having a business located at 398, Hase, Atsugi-shi, Kanagawa-ken 243-0036, Japan, and SHARP KABUSHIKI KAISHA having a business located at 22-22, Nagaike-cho, Abeno-ku, Osaka-shi, Osaka 545 Japan, certify that they are the assignee of the entire right, title, and interest in the above identified application by virtue of an Assignment recorded in the U.S. Patent and Trademark Office at Reel 8475, Frame 0212.

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TECHNOLOGY COTTER 2900 SPECIAL PROGRAM CENTER

Docket No. 07977/108002

Pursuant to 35 CFR \$1.321(b) and to obviate a double patenting rejection, SEMICONDUCTOR ENERGY LABORATORY CO., LTD. and SHARP KABUSHIKI KAISHA, each, individually, and also jointly, hereby waive and disclaim the terminal portion of the term of the entire patent to be granted upon the above identified application subsequent to the expiration date of U.S. Patent No. 6,246,454. Any patent granted on the above identified application and U.S. patent No. 6,246,454 will expire on the same day. Further, any patent granted on the above identified application shall be enforceable only for and during such period that said patent is commonly owen with U.S. Patent No. 6,246,454.

This disclaimer runs with any patent granted on the above identified application and is binding upon the grantee, its successors or assigns.

In making the above disclaimer, SEMICONDUCTOR ENERGY LABORATORY Co.. Ltd. and SHARP KABUSHIKI KAISHA do not disclaim the terminal part of any patent granted on the above identified application that would extend to the expiration date of the full statutory term as defined in 35 U.S.C. 154 to 156 and 173 of the prior patent, as presently shortened by any terminal disclaimer, in the event that it later expires for failure to pay a maintenance fee, is held unenforceable, is found invalid by a court of competent jurisdiction, is statutorily disclaimed in whole or terminally disclaimed under 35 CFR 1.321, has all claims cancelled by a reexamination certificate, is reissued, or is in any manner terminated prior to the expiration of its full statutory term as presently shortened by any terminal disclaimer.

The undersigned has reviewed all the documents in the chain of title of the above identified application and to the best of the undersigned's knowledge and belief, title is in SEMICONDUCTOR ENERGY LABORATORY CO., LTD. and SHARP KABUSHIKI KAISHA.

The undersigned (whose title is supplied below) is empowered to act on behalf of the assignee.

Docket No. 07977/108002

The undersigned hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

02/25/2002

Date

Name: Shunpei Yamazaki

Title: President

Company Name: SEMICONDUCTOR ENERGY

LABORATORY Co., Ltd.

9. Feb. 2002

Date

TERMINAL DISCLAIMER
APPROVED

JUN 0 7 2002

TECHNOLOGY CENTER 2800 SPECIAL PROGRAM CENTER Name: Shigeo Terashima

Title: Group General Manager,

Intellectual Property Group

Company Name: SHARP KABUSHIKI

Shigeo Lerashim

KAISHA

SHARON S. HOPPE PARALEGAL SPECIALIST TECHNOLOGY CENTER 2800